

# L750/850-04A

# Bi-Color LED for Medical Analysis

Bi-color LED of L750/850-04A consists of DDH structure AIGaAs LEDs mounted on a lead frame with a clear epoxy lens.

On forward bias it emits a band of visible light which peaks 750nm and 850nm at anode common.

#### <Features>

- High Reliability
- High Power
- Anode Common

### <Specifications>

Product Name: Bi-color LED
Type Number: L750/850-04A

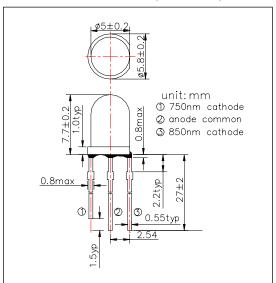
3. Chip:

Chip material: AIGaAs(DDH structure)Peak Wavelength: 750nm and 850nm typ.

4.Package

Type: Φ5mm clear moldingResin Material: Epoxy ResinLead Frame: Soldered(Lead Free)

## Outer Dimension (Unit:mm)



Absolute Maximum Ratings											
Item	Symbol	Maximum F	Rated Value	Linit	Ambient Temperature						
		750nm	850nm	- Unit							
Power Dissipation	PD	200	160	mW	Ta=25℃						
Forward Current	IF	10	00	mA	Ta=25℃						
Reverse Voltage	IR	1	0	V	Ta=25℃						
Operating Temperature	TOPR	-30 ~	+85	$^{\circ}$ C							
Storage Temperature	TSTG	-30 ~	+100	$^{\circ}$ C							
Soldering Temperature	TSOL	26	50	$^{\circ}$ C							

Soldering condition: Soldering condition must be completed within 3 seconds at 260°C

Electro-Optical Characteristics [Ta=25°C]											
Item	Symbol	Condition	Minimum		Typical		Maximum		l læit		
			750	850	750	850	750	850	Unit		
Forward Voltage	VF	IF=50mA			1.85	1.55	2.00	1.70	V		
Reverse Current	IR	VR=5V					10		uA		
Total Radiated Power	РО	IF=50mA	8.0	12.0	15.0	18.0			mW		
Peak Wavelength	λΡ	IF=50mA	730	830	750	850	770	870	nm		
Half Width	Δλ	IF=50mA			30	35			nm		
Viewing Half Angle	θ 1/2	IF=50mA			土	20			Deg.		

Total Radiated Power is measured by Photodyne #500. Radiant Intensity is measured by Tektronix J-6512

